NSN 5961-01-381-8456

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-381-8456 **Inclosure Material:** Metal **Overall Length:** 0.338 inches **Overall Diameter:** 0.625 inches **Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 repetitive peak reverse voltage and 280.0 reverse voltage, total rms and 450.0 nonrepetitive peak reverse voltage **Current Rating Per Characteristic:** 50.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 195.0 degrees celsius junction **Terminal Type And Quantity:** 1 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No